

10/780,572

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	817948	(ferroelectric adj memory) and write and electrode and signal ana matrix	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/13 17:54
L2	384	(ferroelectric adj memory) and write and electrode and signal and matrix	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/13 17:54
L3	70	(ferroelectric adj memory) and write and electrode and signal and matrix and (peripher\$ adj circuit) and information and direction	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/13 17:55
L4	18	(ferroelectric adj memory) and write and electrode and signal and matrix and (peripher\$ adj circuit) and information and direction and array and cell and (first adj signal adj electrode) and (second adj signal adj electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/13 17:57
L5	7	(ferroelectric adj memory) and write and electrode and signal and matrix and (peripher\$ adj circuit) and information and direction and array and cell and (first adj signal adj electrode) and (second adj signal adj electrode) and (intersection adj region)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/13 18:08
L6	1	("6727536").PN.	USPAT	OR	OFF	2005/12/13 18:08
L7	1	("6690598").PN.	USPAT	OR	OFF	2005/12/13 18:09